

# NIU3E Rugged COTS Systems

## Rugged Embedded Multifunction I/O System with 10 GB Fiber Optic & 1 GB **Copper Ethernet Switch**

The NIU3E is a small, rugged, low-power, self-contained multifunction I/O processing system preconfigured with 24-CH programmable Discrete I/O, 8-CH ARINC 429/575, 4-CH CANBus and 2-CH MIL-STD-1553 functions and incorporates an Ethernet switch module that offers four (4) 10GBase-SR multimode fiber optic ports and sixteen (16) 10/100/1000Base-T Ethernet ports. The NIU3E can also be configured with one smart Configurable Open Systems Architecture™ (COSA®) function module. The NIU3E boasts a Dual or Quad Core ARM A53 processor for customer application and I/O and communications management. The NIU3E is configured with two 10/100/1000Base-T (GbE) Ethernet ports and an RS-232 port for maintenance / diagnostic or configuration interface. Ideally suited for rugged Mil-Aero applications, the NIU3E delivers off-the-shelf solutions that accelerate deployment of SWaP-optimized systems in air, land and sea applications.

The NIU3E rugged multifunction I/O and communications processing platform provides scalable system level solutions enabling networks including on-board vehicle, marine and aircraft platforms, to field and expand digital network architectures for network-centric operations.



## **Features**

- Preconfigured Onboard I/O Functions 24-CH Discrete I/O (Enhanced Mode Optional)
  - 8-CH ARINC 429/575

  - 4-CH CAN bus; CAN A/B 2.0, CAN-FD, ARINC-825
    2-CH MIL-STD-1553
- Supports One NAI smart I/O function module 100+ modules to choose from Customer-configurable COSA® architecture
- Minimized SWaP Footprint
- 7.2" x 3.2" x 7.1" (est.)
- (incl. connectors)
- •7.7 lbs 28 VDC @ ~0.675 A (est.) + Module Power

- Xilinx Zynq UltraScale+ SoC with Dual/Quad Core ARM A53 8 GB DDR4 RAM
  - ^ 32 GB SATA Flash
- Supports ES2 Managed Switch Module 16x 10/100/1000Base-T (GbE)
- 4x 10GBase-SR Fiber 1x RS-232 debug port
- Connectivity
- 1x RS-232 debug port
- 2x USB 2.0 0
- Power Supply Hold-up (Optional)
- 50+ milliseconds of Holdup time Certifiable
  - DO-178C & DO-254 DAL A (Contact Factory)

- Cybersecurity & Anti-Tamper FIPS-140-3 Level 3 (Contact Factory)
- Continuous Background BIT
- Operating System Support
  Xilinx PetaLinux

  - Wind River VxWorks 7.x
- DDC-I Deos
- Rugged applications\*
  MIL-STD-810
- MIL-STD-461
- Operating temp: -40°C to +71°C
- Conduction-cooled and Convection/Air-cooled options (contact factory)

\*Designed to meet. Characterizations pending. EMI/EMC requires shielded cables and proper grounding practices.

NIU3E Data Sheet Rev B5



## Select up to 3 independent functions for your application

I/O Modules										
Function	Module	Description	Function	Module	Description					
Analog-to-Digital	AD1	12 CH. A/D, ±10 V, Dedicated, 256 kHz (max), Sigma-Delta	Digital IO - Differential	<u>DF1</u>	16 CH. Differential I/O, Input: -10 V to +10 V (422), -7 V to +12 V (485) Output:25 V to +5 V					
	<u>AD2</u>	12 CH. A/D, ±100 V (max), Dedicated, 256 kHz (max), Sigma-Delta	Transceiver	DF2	16 CH. 16 Channel Enhanced Differential I/O					
	AD3	12 CH. A/D, ±25 mA, Dedicated, 256 kHz (max), Sigma-Delta		<u>DT1</u>	24 CH. Discrete I/O, 0-60 VDC Input/Output, Max lout 500 mA - 2 A, Source/Sink (out)					
	<u>AD4</u>	16 CH. A/D, ± 10 V, Multiplexed, 500 KHz Agg / 8 Ch, SAR		<u>DT2</u>	16 CH. Discrete I/O, $\pm 80$ V Input/Output, Max lout 600 mA, Isolated/Ch Switch (out)					
	<u>AD5</u>	16 CH. A/D, ± 50 V, Multiplexed, 500 KHz Agg / 8 Ch, SAR	Discrete IO - Multichannel,Programmable	DT3	4 CH. Discrete Hi & Lo Side Switch Output @ 65V/2A (max), external individual supplied VCC & VSS per channel pair					
	<u>AD6</u>	16 CH. A/D, ± 100 V, Multiplexed, 500 KHz Agg / 8 Ch, SAR		<u>DT4</u>	24 CH. Enhanced DT1					
	<u>ADE</u>	16 CH. A/D, ±10 V, Individual 16-bit SAR, 200 kHz max., Simultaneous Sampling		<u>DT5</u>	16 CH. Enhanced DT2					
	<u>ADF</u>	16 CH. A/D, ±100 V, Individual 16-bit SAR, 200 kHz max., Simultaneous Sampling	Dalari	<u>RY1</u>	4 CH. Relay, 220V/2A @ 60W/62.5VA (Max), Non Latching					
Chip Detector and Fuzz Burn	<u>CD1</u>	6 CH. Chip Detector (CD) and Fuzz Burn (FB)	Relay	<u>RY2</u>	4 CH. Relay, 220V/2A @ 60W/62.5VA (Max), Latching					
Digital-to-Analog	<u>DA1</u>	12 CH. D/A, ± 10 V, 25 mA Per Channel, Current or Voltage Control		<u>TL1</u>	24 CH. TTL I/O, Standard Functionality, Programmable					
	<u>DA2</u>	16 CH. D/A, ± 10 V, 10 mA Per Channel, No Current Control	Digital IO - TTL,CMOS	<u>TL2</u>	24 CH. TTL I/O, Enhanced Functionality, Programmable					
	<u>DA3</u>	4 CH. D/A, ±40 V, ±100 mA, Voltage or Current Output	Variable Reluctance	<u>VR1</u>	8 CH. Variable Reluctance Signal Input and General- Purpose Pulse Counter, ±100 V, 100 kHz (max)					
	DA4	4 CH. D/A, ± 20 to ± 80, 10 mA, Voltage Control Only								
Measurement & Simulation Modules										
Function	Module	Description	Function	Module	Description					
AC Reference	AC2	2 CH. AC Reference Source, 47 Hz - 20 KHz, ± 3% Acc, 2 – 28 Vrms, 6 VA (Max/Ch) Power		<u>LD4</u>	4 CH. LVDT/RVDT to Digital, 2-28 Vrms Input, 2-115 Vrms Exc, 10 KHz - 20 KHz Freq					
	AC3	2 CH. AC Reference Source, 47 Hz - 2.5 KHz, ± 3% Acc, 28 – 115 Vrms, 6 VA (Max/Ch) Power	LVDT RVDT Measurement and Simulation	<u>LD5</u>	4 CH. LVDT/RVDT to Digital, 28-90 Vrms Input, 2-115 Vrms Exc, 47 Hz - 1 KHz Freq					
Synchro Resolver Measurement and Simulation	<u>DSK</u>	3 CH. Digital to Synchro, 2-28 VLL, 2-115 Vrms Exc, 1 KHz - 5 KHz Freq, .5 VA/Ch (Max)		<u>RT1</u>	8 CH. Resistance Temperature Detectors (RTD), 2, 3, or 4 wire, 16 Bit Res, 16.7 Hz/Ch					
LVDT RVDT Measurement and Simulation	<u>LD1</u>	4 CH. LVDT/RVDT to Digital, 2-28 Vrms Input, 2-115 Vrms Exc, 47 Hz -1 KHz Freq	Thermocouple and RTD Measurement	<u>TC1</u>	8 CH. Thermocouple, 4.17 - 470 Hz, ±100 mV A/D					
	<u>LD2</u>	4 CH. LVDT/RVDT to Digital, 2-28 Vrms Input, 2-115 Vrms Exc, 1 KHz - 5 KHz Freq		<u>TR1</u>	8 CH. Thermocouple (TCx) & Resistance Temperature Detectors (RTD), programmable per channel					
	LD3	4 CH. LVDT/RVDT to Digital, 2-28 Vrms Input, 2-115 Vrms Exc, 5 KHz - 10 KHz Freq	Strain Gauge Measurement	<u>SG1</u>	4 CH. Strain Gauge, 4.7 Hz - 4.8 KHz, Measurement, Conventional 4-Arm Bridge					



Communication Modules										
Function	Module	Description		Function	Module	Description				
ARINC Communications	<u>AR1</u>	12 CH. ARINC 429, 100 KHz or 12.5 KHz, RX/TX, 256 Word Tx/Rx Buffer		MIL-STD-1553B	<u>FTC</u>	4 CH. MIL-STD-1553 (AMC), BC, RT, BM, BM/RT, 128 KB RAM Per Channel, Transformer Coupled				
	AR2	1 CH. ARINC 568 (CH-1, RX & TX) & 1 Channel ARINC 579 (CH-2, Programmable RX or TX), 1024-Word TX & RX Buffers per Ch.			<u>FTD</u>	1 CH. MIL-STD-1553 (AMC), BC, RT, BM, BM/RT, 128 KB RAM, Direct Coupled				
CANBus Communications	<u>CB1</u>	8 CH. CANBus, CAN 2.0 A/B, 16 K RX/TX Buffer, 1 Mb/s Max Data Rate			<u>FTE</u>	2 CH. MIL-STD-1553 (AMC), BC, RT, BM, BM/RT, 128 KB RAM Per Channel, Direct Coupled				
	<u>CB2</u>	8 CH. CANBus, J1939, 16 K RX/TX Buffer, 500 kb/s Max Data Rate			<u>FTF</u>	4 CH. MIL-STD-1553 (AMC), BC, RT, BM, BM/RT, 128 KB RAM Per Channel, Direct Coupled				
	<u>CB3</u>	8 CH. CANBus, CAN 2.0 A/B (CB1) or J1939 (CB2) protocol layer programmable per channel		MIL OTD 4700	<u>FTJ</u>	1 CH. MIL-STD-1760 (1553), BC, RT, BM, BM/RT, 128 KB RAM, Transformer Coupled				
Ethernet NIC Interface	<u>EM1</u>	2 CH. Dual Ethernet I/F, Intel 82850, 10/100/1000		MIL-STD-1760	<u>FTK</u>	2 CH. MIL-STD-1760 (1553), BC, RT, BM, BM/RT, 128 KB RAM Per Channel, Transformer Coupled				
Ethernet Switch	<u>ES2</u>	16 CH. (Ports) Ethernet Switch, 10/100/1000Base-T (GbE), Layer 2+/3 Managed			<u>SC1</u>	4 CH. Serial, RS-232/422/423 (MIL-STD-188C)/485, Non Isolated				
	<u>ES2</u>	16 CH. (Ports) (max.) Ethernet Switch, 10/100/1000Base-T (GbE), 4 x Fiber Optic Ports (opt.), Layer 2+/3 Managed		Serial	<u>SC3</u>	8 CH. (max) RS-232/422/485 Serial Communications or GPIO, Programmable, Non-isolated				
MIL-STD-1553B	<u>FTA</u>	1 CH. MIL-STD-1553 (AMC), BC, RT, BM, BM/RT, 128 KB RAM, Transformer Coupled		Communications	<u>SC5</u>	4 CH. RS-232/422/485 communications, isolated per channel and from SYS GND				
	<u>FTB</u>	2 CH. MIL-STD-1553 (AMC), BC, RT, BM, BM/RT, 128 KB RAM Per Channel, Transformer Coupled			<u>SC6</u>	4 CH. RS-232/422/485 communications, individual SYS GND provided per channel (non-isolated)				
Storage										
Function	Module	Description		Function	Module	Description				
SATA Solid State Drive (SSD)	<u>FM2</u>	1 CH. 480 GB MLC SATA Flash, extended temp -40°C to 85°C operation		SATA Solid State Drive (SSD)	<u>FM9</u>	1 CH. 1.92 TB SATA TLC NAND Flash, Extended Temperature Operation				
Combination Modules										
Function	Module	Description		Function	Module	Description				
Combo	<u>CM5</u>	2 CH. Dual-redundant MIL-STD-1553 & 8 Channel ARINC 429/575, 100 KHz or 12.5 KHz, RX or TX, 256 Word Tx/Rx Buffer		Combo	<u>CM8</u>	2 CH. Dual-redundant MIL-STD-1553 & 12 Channel Discrete I/O, 0-60 VDC Input/Output, Max Iout 500 mA - 2 A, Source/Sink (out)				

## Architected for Versatility

NAI's Configurable Open Systems Architecture <sup>™</sup> (COSA®) offers a choice of over 100 smart I/O, communications, or Ethernet switch functions, providing the highest packaging density and greatest flexibility of ruggedized embedded product solutions in the industry. Preexisting, fully-tested functions can be combined in an unlimited number of ways quickly and easily.

## **One-Source Efficiencies**

Eliminate man-months of integration with a configured, field-proven system from NAI. Specification to deployment is a seamless experience as all design, state-of-the-art manufacturing, assembly and test are performed - by one trusted source. All facilities are located within the U.S. and optimized for high-mix/low volume production runs and extended lifecycle support.

## Product Lifecycle Management

From design to production and beyond, NAI's product lifecycle management strategy ensures the long-term availability of COTS products through configuration management, technology refresh and obsolescence component purchase and storage.



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